

**VOLTAGE RANGE: 100 - 600V**

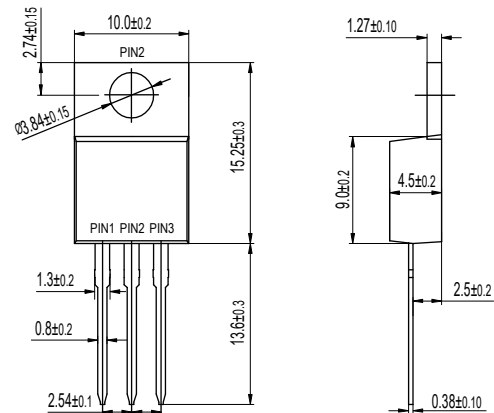
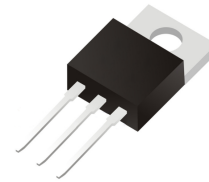
**CURRENT: 10A**

### Features

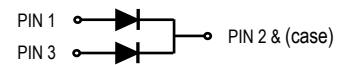
- Glass passivated chip junctions
- Super fast recovery time for switching mode application
- High Forward Surge Capability
- Low Reverse Current
- Lead free in compliance with EU RoHS 2011/65/EU directive

### Mechanical Data

- Circuit figure: Common Cathode
- Leads: Solderable per mil-std-202, Method 208
- Polarity: as marked
- Mounting torque: 5 in-lbs maximum
- Terminals: Puretin plated
- Weight: TO-220AB 1.85 grams



TO-220AB



### Maximum Ratings And Electrical Characteristics $T_A = 25^\circ\text{C}$

RATINGS	SYMBOL	SF 1001CT	SF 1002CT	SF 1003CT	SF 1004CT	SF 1005CT	SF 1006CT	UNIT
Maximum repetitive reverse voltage	VRRM	100	200	300	400	500	600	V
Maximum RMS voltage	VRMS	70	140	210	280	350	420	V
Maximum DC blocking voltage	VDC	100	200	300	400	500	600	V
Maximum average forward current	I <sub>AV</sub>	10						A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	150						A
Typical thermal resistance per diode (Note 1)	R <sub>θ-JC</sub>	2.5						°C/W
Operating junction temperature range	T <sub>J</sub>	-55 to +150						°C
Storage temperature range	T <sub>STG</sub>	-55 to +150						°C
Typical forward voltage per leg at 5A	V <sub>F</sub>	1.00		1.30		1.70		V
Maximum average reverse current at rated DC blocking voltage	I <sub>R</sub>	5 250						μA
Typical reverse recovery time (Note 2)	T <sub>RR</sub>	35						nS

Notes: 1. Thermal resistance from junction to case.  
2. Test conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A.

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

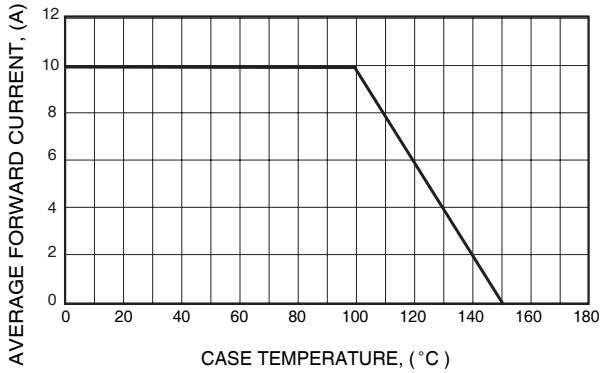


FIG. 3 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

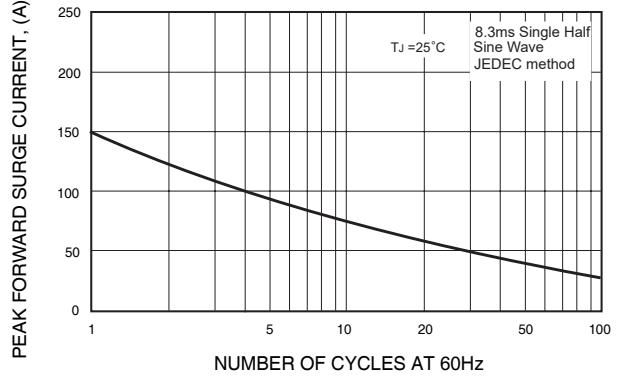


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

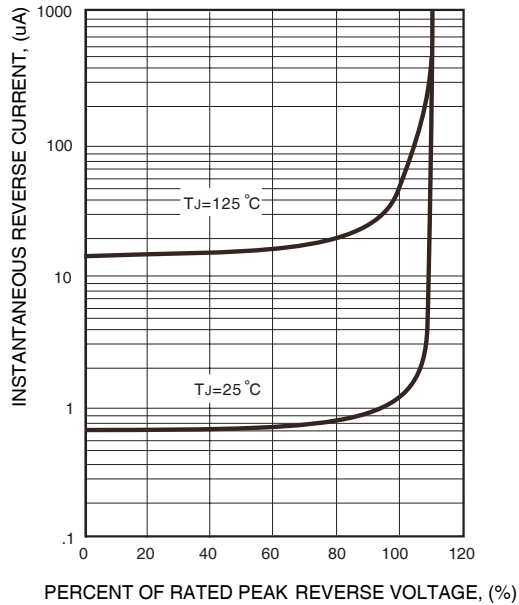


FIG. 2 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

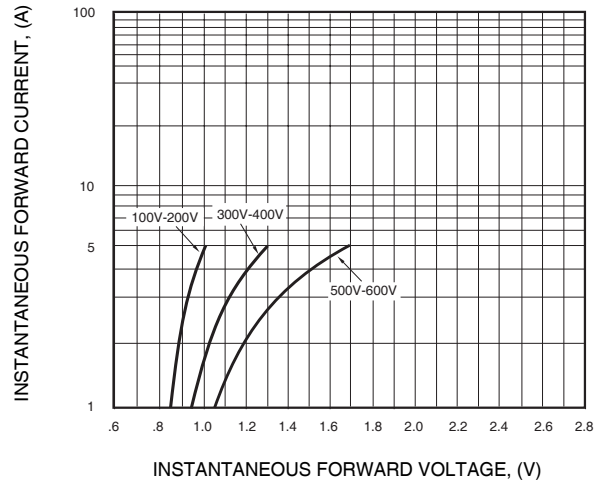
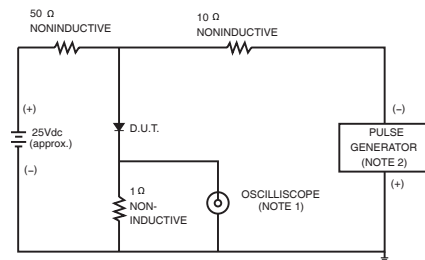


FIG.6- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.  
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

